TXC CORPORATION

4F, NO. 16, Sec. 2 Chung Yang S Rd., Peitou, Taipei, Taiwan.

TEL : 886-2-2894-1202 , 886-2-2895-2201 FAX : 886-2-2894-1206 , 886-2-2895-6207 www.txccorp.com

SPECIFICATION FOR APPROVAL

CUSTOMER	:	
PRODUCT TYPE	:	SMD TSX 2.0*1.6
NOMINAL FREQ.	:	19.200000MHz
TXC P/N	:	OY19270003
REVISION	:	A1
CUSTOMER P/N	:	
PM / SALES	:	
DATE	:	

CUSTOMER SIGNATURE & Date

(1) TXC requires one copy returned with signature and title of authorized individual that signifies acceptance of the attached specifications.

(2) Orders received and accepted by TXC after return of signed copy of specification will be produced per these specifications.

(3) Any changes to these specifications must be agreed upon by both parties and new revision of the Product Specification Sheet will be issued.

(4) Any issuance of purchase order prior to consigning back the Approval page of "Specification Sheets" from customers will be regarded as the agreement on the contents of these specifications.

Attachment: Product Specification Sheet

1

2

3

4

5

RoHS Compliant

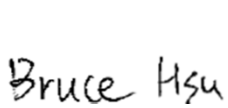
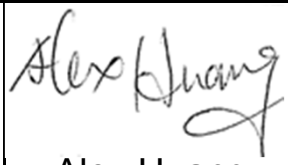
TXC CORPORATION

4F, NO. 16, Sec. 2 Chung Yang S Rd., Peitou, Taipei, Taiwan.

TEL : 886-2-2894-1202 , 886-2-2895-2201 FAX : 886-2-2894-1206 , 886-2-2895-6207 www.txccorp.com

PRODUCT SPECIFICATION SHEET

PRODUCT TYPE	:	SMD TSX 2.0*1.6
NOMINAL FREQ.	:	19.200000MHz
TXC P/N	:	OY19270003
REVISION	:	A1

PE/RD	QA	MFG
		
Bruce Hsu	Alex Huang	Rick Lo
13-Aug-14	*13-Aug-14*	*13-Aug-14*

NOTE:

(1) The green product standard set by TXC is based upon the international standards. Related information is publicly described on the TXC's Website, and updated regularly. The document is compliant with the latest green product quality system directives at the time.

(2) Revision "Sx" is for engineering samples only. PE/RD's approval required.

(3) Revision "Ax" is production ready. PE, QA and MFG's approval required.

RoHS Compliant

Rev	Revise page	Revise contents	Date	Ref.No.	Reviser
A1	N/A	Initial released	13-Aug-14	N/A	Yachuan Miao

■ ELECTRICAL SPECIFICATIONS

Standard atmospheric conditions

Unless otherwise specified, the standard range of atmospheric conditions for making measurement and tests are as follow:

Ambient temperature : 25±10℃

Relative humidity : 40%~70%

If there is any doubt about the results, measurement shall be made within the following limits:

Ambient temperature : 25±3℃

Relative humidity : 40%~70%

Measure equipment

Electrical characteristics measured by S&A 250B or equivalent.

Crystal cutting type

The crystal is using AT CUT (thickness shear mode).

Weight:

0.0086g / piece(TYP), 26 ± 1.3 g /3 kpcs(regardless of tape weight)

	Parameters	Symbol	Electrical Spec.				Condition	Notes
			Min.	Typ.	Max.	Units		
1	Nominal Frequency	FL		19.200000		MHz	-	-
2	Oscillation Mode	-		Fundamental		-	-	-
3	Load Capacitance	CL		7		pF	-	1
4	Frequency Tolerance	-		±10		ppm	+25℃ ± 3℃	-
5	Frequency Stability Over Operating Temp. Range(Reference 25°C)	-		±12		ppm	-30℃~+ 85℃	2
6	Frequency drift after reflow	-	-	-	±2	ppm	After two reflows	-
7	Operating Temperature	-	-30	~	105	℃	-	-
8	Aging	-	-	-	±0.7	ppm/year	-	-
9	Drive Level	DL	10	-	100	uW	-	-
10	Equivalent Series Resistance	ESR	-	-	80	Ω	-	-
11	Shunt Capacitance C0	C0	0.3	~	1.3	pF	-	-
12	Motional Capacitance C1	C1	1.2	~	3.1	fF	-	-
13	Insulation Resistance	-	500	-	-	MΩ	at DC 100V	-
14	Storage Temperature Range	-	-40	~	105	℃	-	-
15	Spurious Mode Series Resistance	-	1100	-	-	Ω	±1MHz	-
16	Q Factor	Q	75000	-	-	-	-	3
17	First-order Curve Fitting Parameter	-	-0.4	-	-0.1	ppm/℃	-	4
18	Second-order Curve Fitting Parameter	-	-4.5	0	4.5	$x10^{-4}$ ppm/℃^{2}	-	4
19	Third-order Curve Fitting Parameter	-	8.5	10	11.5	$x10^{-5}$ ppm/℃^{3}	-	4
20	Residual Frequency stability slope	-	-	-	±50	ppb/℃	-	5
21	5℃ small orbit hysteresis 1	-	-	-	±50	ppb/℃	-	6
22	5℃ small orbit hysteresis 2	-		100		ppb pk-pk	-	7
23	Inflection Point	-	30.5	~	33.5	℃	$t = (t_0 - \frac{C2}{3C3})$	-

	Parameters	Symbol	Electrical Spec.				Condition	Notes
			Min.	Typ.	Max.	Units		
24	DLD Freq (Max-Min)	-	-	-	3.0	ppm	-	8
25	DLD Freq (Repeatability)	-	-	-	0.7	ppm	-	8
26	DLD ESR (Max-Min)	-	-	-	20	%	-	8
27	DLD ESR (Repeatability)	-	-	-	10	%	-	8

Note 1 The load capacitance is measured according to IEC Standard #60444-7

Note 2 Above 85°C tolerance over temperature bound by third-order coefficient range

Note 3 Minimum Q value calculated from ESR and L is smaller than this specification

Note 4 The curve fitting parameter is obtained from the Qualcomm crystal curve fitting algorithm, t0=32 °C (Refer to Curve Fitting Calculation Table: 80-V9690-23 Rev.C)

Note 5 Condition 1A – Test condition (continuous temperature rate change of ~1.0°C/min):

- ☐ Measure FT points every 1°C, heating up from -30 to +85°C, subtract a fifth-order polynomial best fit and then calculate the slope of the residual.
- ☐ The residual slope should be within ±50 ppb/°C.

Note 6 Condition 1B – Hysteresis 1 test condition (continuous temperature rate change of ~1.0°C/min):

- ☐ Measure FT points every 0.5°C while cycling temperature over a 5°C small temperature orbit; an example 5°C small orbit temperature cycle is +30°C to +35°C to +30°C.
- ☐ During every individual heating/cooling cycle there should be 11 points; discard the first point of each heating and cooling cycle; this leaves 10 points for each heating and cooling cycle. Subtract the fifth- order polynomial best fit from 1A for each of the 10 points, and then calculate the slope of the residual for each of these heating and cooling 10 point curves.
- ☐ The residual slope should be within ±50 ppb/°C.

Note 7 Condition 2 – Hysteresis 2 test condition (continuous temperature rate change of ~1.0°C/min):

- ☐ Measure FT points every 0.5°C while cycling temperature over a 5°C small temperature orbit; an example 5°C small orbit temperature cycle is +30°C to +35°C to +30°C.
- ☐ During every individual heating/cooling cycle there should be 11 points; discard the first and last point of each heating and cooling cycle, which results in 9 temperature points. Calculate the average measured peak-to-peak frequency difference for these 9 temperature points.
- ☐ The average difference is the magnitude of the small orbit hysteresis 2.

Note 8 0.01 uW to 100 uW to 0.01 uW, number of points: 15 points up and 15 points down = 29 total data points

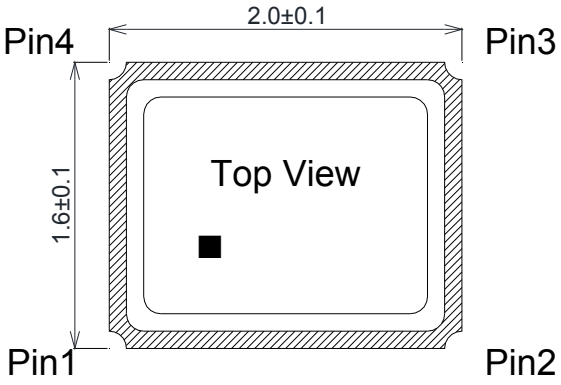
Note 9 This crystal specification complies to Qualcomm Mini-Specification 80-V9690-26 Rev.D

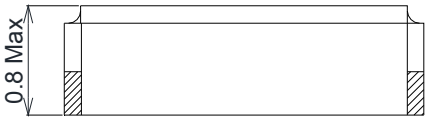
■ NTC THERMISTOR ELECTRICAL SPECIFICATIONS

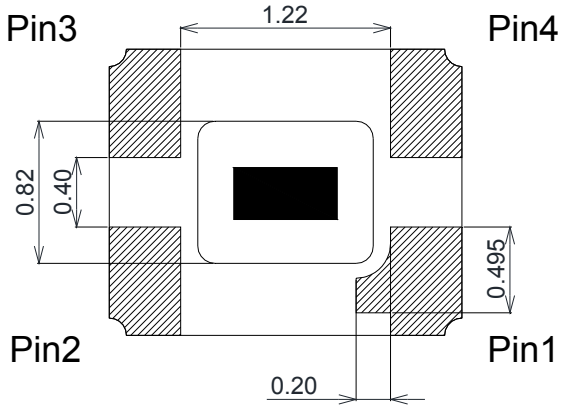
	Parameters	Symbol	Electrical Spec.				Notes
			Min.	Typ.	Max.	Units	
1	Resistance (25 ℃)	-		100k±1%		Ω	-
2	B-Constant (25-50 ℃)	-		4250±1%		K	The B constant is calculated using the zero-power resistance values measured at 25℃ and 50℃
3	Operating Temperature	-	-30	~	105	℃	-

■ **DIMENSIONS**

(Unit:mm)





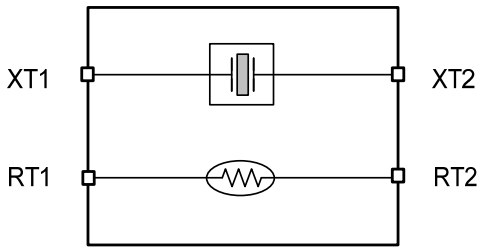


■PIN FUNCTION

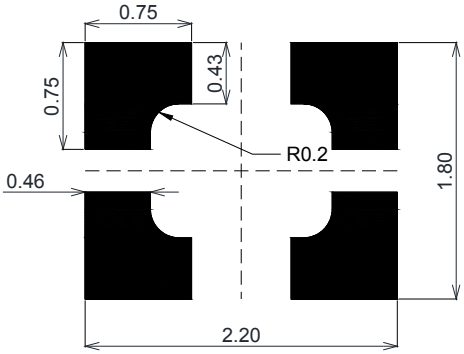
	Symbol	Function
Pin 1	XT1	XTAL Terminal 1
Pin 2	RT2	Thermistor Terminal 2
Pin 3	XT2	XTAL Terminal 2
Pin 4	RT1	Thermistor Terminal 1

Note: Pin 2 is connected to the metal lid and thermistor
Pin 4 is connected to the thermistor only

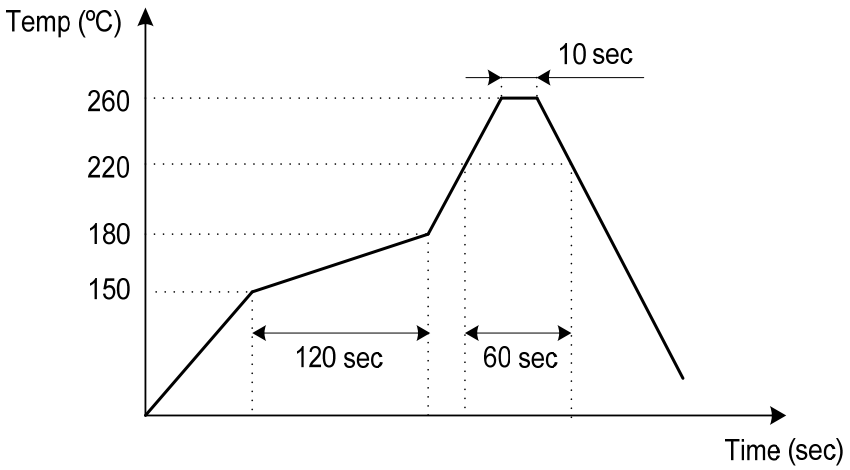
■BLOCK DIAGRAM



■ SUGGESTED LAYOUT

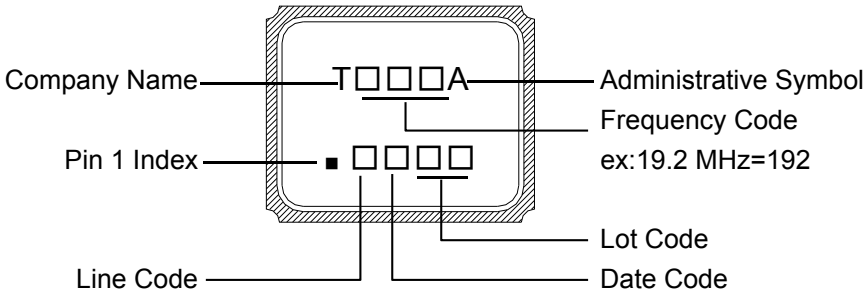


■ SUGGESTED REFLOW PROFILE



Note : Total Time: 200 sec. Max., Solder Melting Point: 220°C

■ MARKING



Date Code:

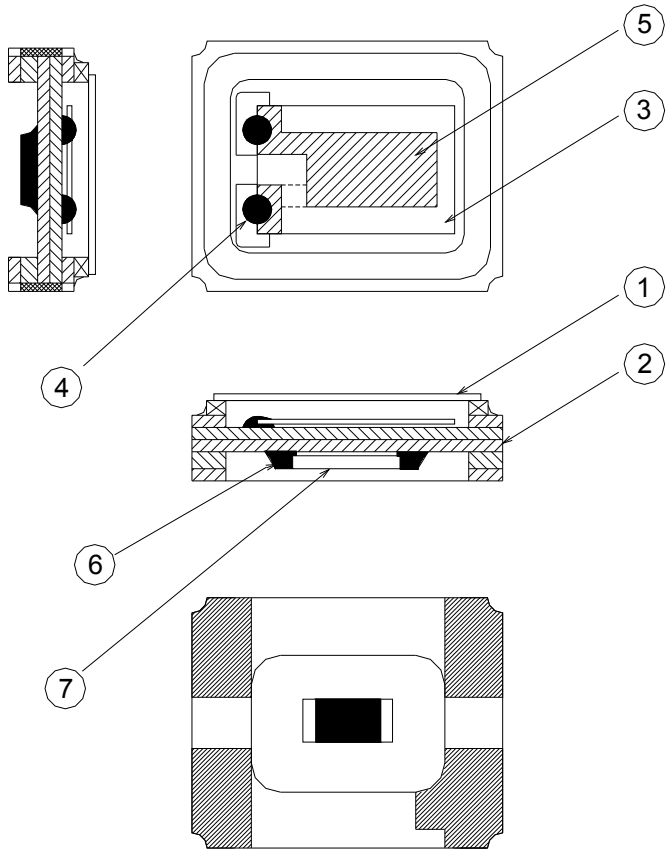
YEAR \ MONTH				1 JAN	2 FEB	3 MAR	4 APR	5 MAY	6 JUN	7 JUL	8 AUG	9 SEP	10 OCT	11 NOV	12 DEC
2005	2009	2013	2017	A	B	C	D	E	F	G	H	J	K	L	M
2006	2010	2014	2018	N	P	Q	R	S	T	U	V	W	X	Y	Z
2007	2011	2015	2019	a	b	c	d	e	f	g	h	j	k	l	m
2008	2012	2016	2020	n	p	q	r	s	t	u	v	w	x	y	z

*This date code will be cycled every four years

Production location:Taiwan

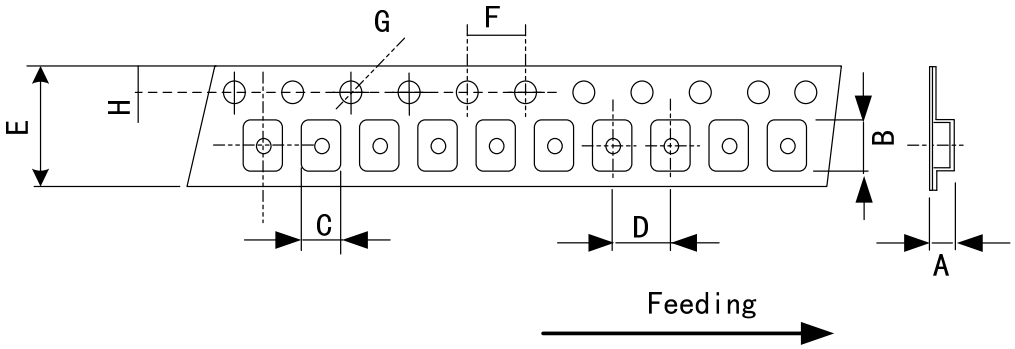
■ STRUCTURE ILLUSTRATION

Crystal Enclosure Seal : Seam Welding



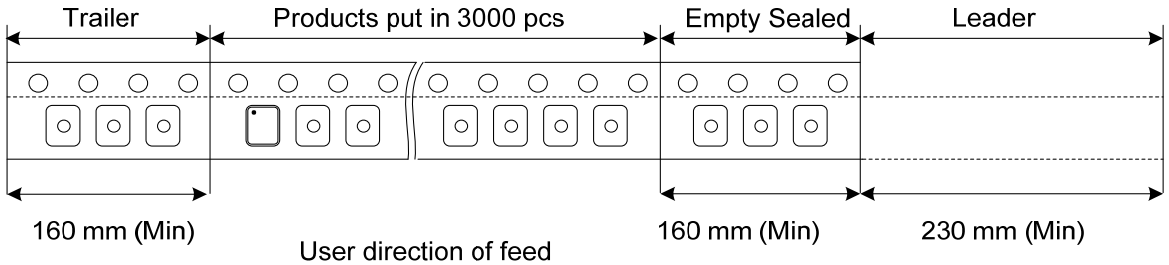
NO	COMPONENTS	MATERIALS	FINISH/SPECIFICATIONS
1	Lid	Metal (Fe+Co+Ni)	-
2	Base(Package)	Ceramic (Al2O3) + Kovar (Fe+Co+Ni)+Ag/Cu	Alumina ceramics
3	Crystal blank	SiO2	-
4	Conductive adhesive	Ag	Silicone resin
5	Electrode	Noble Metal	-
6	Solder	Sn	-
7	Thermistor	Al_2O_3, Ag, Ni	-

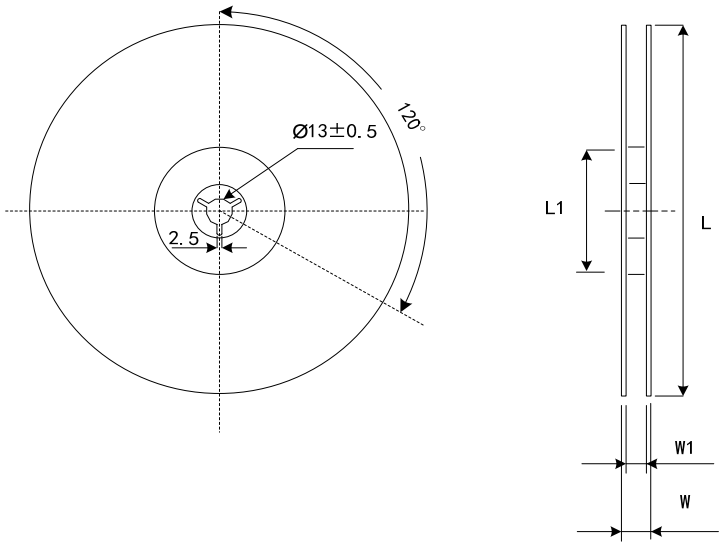
■ PACKING



	A	B	C	D	E	F	G	H	
DIMENSIONS	0.90 ±0.10	2.30 ±0.10	1.90 ±0.10	4.00 ±0.10	8.00 ±0.20	4.00 ±0.10	1.55 ±0.05	1.75 ±0.10	(UNIT:mm)

REMARK :





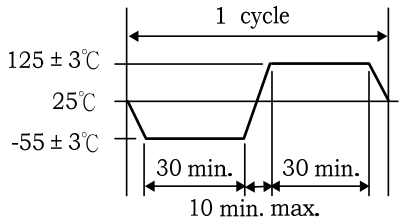
	L	L1	W	W1	
DIMENSIONS	178 ±1.00	60.2 ±0.50	11.5 ±0.2	8 +1/-0	Standard Reel Quantity is 3,000 pcs per reel (UNIT:mm)

■ RELIABILITY SPECIFICATIONS

1.Mechanical Endurance

No.	Test Item	Methods		REF.DOC
1.1	Drop Test	150 cm height, 3 times on concrete floor.		JIS C6701
1.2	Mechanical Shock	Device are shocked to half sine wave (1000 G) three mutually perpendicular axes each 3 times. 0.5m sec. duration time		MIL-STD-202
1.3	Vibration	Frequency range Amplitude Sweep time perpendicular axes each test time	10 ~ 2000 Hz 1.52 mm/20G 20 minutes 4 Hrs (Total test time 12 Hrs)	MIL-STD-883
1.4	Gross Leak	Standard Sample For Automatic Gross Leak Detector, Test Pressure: 2kg / cm^2		MIL-STD-883
1.5	Fine Leak	Helium Bombing 4.5 kg/ cm^2 for 2 Hrs		
1.6	Solder ability	Temperature Immersing depth Immersion time Flux	245 ℃ ± 5℃ 0.5 mm minimum 5 ± 1 seconds Rosin resin methyl alcohol solvent (1 : 4)	MIL-STD-883

2.Environmental Endurance

No.	Test Item	Methods		REF. DOC
2.1	Resistance To Soldering Heat	Pre-heat temperature Pre-heat time Test temperature Test time	125 ℃ 60 ~ 120 sec. 260 ± 5 ℃ 10 ± 1 sec.	MIL-STD-202
2.2	High Temp. Storage	+ 125 ℃ ± 3 ℃ for 500 ± 12 Hrs		MIL-STD-883
2.3	Low Temp. Storage	- 40 ℃ ± 3 ℃ for 500 ± 12 Hrs		
2.4	Thermal Shock	Total 100 cycles of the following temperature cycle 		MIL-STD-883
2.5	High Temp＆Humidity	85℃ ± 3℃, RH 85% , 500 Hrs		EIA-JESD22